



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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TECHNOLOGY CENTER 2800

Application No. : 10/008,204
Applicant : Geeng-Chuan Chern et al.
Filed : December 5, 2001
TC/A.U. : 2826
Examiner : Pershelle L. Greene
Title : METHOD OF FORMING DIFFERENT OXIDE THICKNESS
FOR HIGH VOLTAGE TRANSISTOR AND MEMORY CELL
TUNNEL DIELECTRIC

Docket No. : 2102397-991220
Customer No. : 26379

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on July 31, 2003.

GRAY CARY WARE & FREIDENRICH Date: 07/31/03

By: Kathleen LaBrie

Kathleen LaBrie

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RESPONSE TO OFFICE ACTION OF APRIL 23, 2003

Sir:

In response to the Office Action of April 23, 2003, please enter the following remarks/arguments for the above identified application:

The pending Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 6 of this paper.